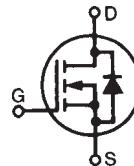


# PolarHV™ HiPerFET Power MOSFET

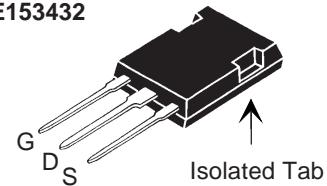
(Electrically Isolated Back Surface)

N-Channel Enhancement Mode  
Avalanche Rated  
Fast Intrinsic Diode



$V_{DSS}$	=	800	V
$I_{D25}$	=	13	A
$R_{DS(on)}$	$\leq$	420	$m\Omega$
$t_{rr}$	$\leq$	200	ns

ISOPLUS247 (IXFR)  
 E153432



G = Gate      D = Drain  
S = Source

Symbol	Test Conditions	Maximum Ratings		
$V_{DSS}$	$T_J = 25^\circ C$ to $150^\circ C$	800	V	
$V_{DGR}$	$T_J = 25^\circ C$ to $150^\circ C$ ; $R_{GS} = 1 M\Omega$	800	V	
$V_{GSS}$	Continuous	$\pm 30$	V	
$V_{GSM}$	Transient	$\pm 40$	V	
$I_{D25}$	$T_c = 25^\circ C$	13	A	
$I_{DM}$	$T_c = 25^\circ C$ , pulse width limited by $T_{JM}$	55	A	
$I_{AR}$	$T_c = 25^\circ C$	12	A	
$E_{AR}$	$T_c = 25^\circ C$	50	$mJ$	
$E_{AS}$	$T_c = 25^\circ C$	1.5	J	
$dv/dt$	$I_s \leq I_{DM}$ , $di/dt \leq 100 A/\mu s$ , $V_{DD} \leq V_{DSS}$ , $T_J \leq 150^\circ C$ , $R_G = 2 \Omega$	10	V/ns	
$P_D$	$T_c = 25^\circ C$	208	W	
$T_J$		-55 ... +150	$^\circ C$	
$T_{JM}$		150	$^\circ C$	
$T_{stg}$		-55 ... +150	$^\circ C$	
$T_L$	1.6 mm (0.062 in.) from case for 10 s	300	$^\circ C$	
$T_{SOLD}$	Plastic body for 10 s	260	$^\circ C$	
$V_{ISOL}$	50/60 Hz, RMS, 1 minute	2500	V~	
$F_c$	Mounting force	20..120/4.6..27	N/lb	
Weight		5	g	

## Features

- Silicon chip on Direct-Copper-Bond substrate
  - High power dissipation
  - Isolated mounting surface
  - 2500V electrical isolation
- International standard package
- Fast recovery diode
- Unclamped Inductive Switching (UIS) rated
- Low package inductance
  - easy to drive and to protect

Symbol	Test Conditions ( $T_J = 25^\circ C$ , unless otherwise specified)	Characteristic Values			Advantages
		Min.	Typ.	Max.	
$BV_{DSS}$	$V_{GS} = 0 V$ , $I_D = 250 \mu A$	800		V	
$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 4 mA$	3.0		5.0 V	
$I_{GSS}$	$V_{GS} = \pm 30 V$ , $V_{DS} = 0 V$			$\pm 100 nA$	
$I_{DSS}$	$V_{DS} = V_{DSS}$ $V_{GS} = 0 V$			25 $\mu A$ 1000 $\mu A$	
$R_{DS(on)}$	$V_{GS} = 10 V$ , $I_D = I_T$ (note 1) Pulse test, $t \leq 300 \mu s$ , duty cycle $d \leq 2 \%$			420 $m\Omega$	

## Symbol Test Conditions

## Characteristic Values

(T<sub>J</sub> = 25°C, unless otherwise specified)

Min. Typ. Max.

<b>g<sub>fs</sub></b>	V <sub>DS</sub> = 20 V; I <sub>D</sub> = I <sub>T</sub> , pulse test	15	25	S
<b>C<sub>iss</sub></b> <b>C<sub>oss</sub></b> <b>C<sub>rss</sub></b>	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 25 V, f = 1 MHz	7200	pF	
		470	pF	
		26	pF	
<b>t<sub>d(on)</sub></b> <b>t<sub>r</sub></b> <b>t<sub>d(off)</sub></b> <b>t<sub>f</sub></b>	V <sub>GS</sub> = 10 V, V <sub>DS</sub> = 0.5 V <sub>DSS</sub> , I <sub>D</sub> = I <sub>T</sub> R <sub>G</sub> = 2 Ω (External)	32	ns	
		27	ns	
		75	ns	
		24	ns	
<b>Q<sub>g(on)</sub></b> <b>Q<sub>gs</sub></b> <b>Q<sub>gd</sub></b>	V <sub>GS</sub> = 10 V, V <sub>DS</sub> = 0.5 V <sub>DSS</sub> , I <sub>D</sub> = I <sub>T</sub>	105	nC	
		30	nC	
		33	nC	
<b>R<sub>thJC</sub></b>			0.6 °C/W	
<b>R<sub>thcs</sub></b>		0.15		°C/W

Note 1: Test current I<sub>T</sub> = 12 A

## Source-Drain Diode

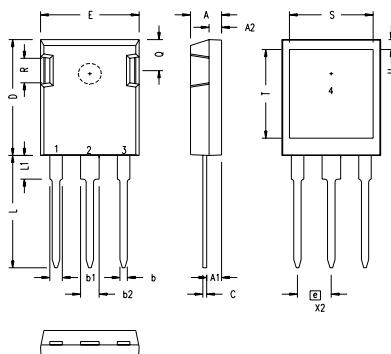
## Characteristic Values

(T<sub>J</sub> = 25°C, unless otherwise specified)

Min. Typ. Max.

<b>I<sub>s</sub></b>	V <sub>GS</sub> = 0 V		24	A
<b>I<sub>SM</sub></b>	Repetitive		55	A
<b>V<sub>SD</sub></b>	I <sub>F</sub> = I <sub>s</sub> , V <sub>GS</sub> = 0 V, Pulse test, t ≤ 300 μs, duty cycle d ≤ 2 %		1.5	V
<b>t<sub>rr</sub></b> <b>Q<sub>RM</sub></b>	I <sub>F</sub> = 25A, -di/dt = 100 A/μs V <sub>R</sub> = 100V, V <sub>GS</sub> = 0 V		250	ns
			0.8	μC
			6.0	A

## ISOPLUS247 (IXFR) Outline



SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.190	.205	4.83	5.21
A1	.090	.100	2.29	2.54
A2	.075	.085	1.91	2.16
b	.045	.055	1.14	1.40
b1	.075	.084	1.91	2.13
b2	.115	.123	2.92	3.12
C	.024	.031	0.61	0.80
D	.819	.840	20.80	21.34
E	.620	.635	15.75	16.13
e	.215 BSC		5.45 BSC	
L	.780	.800	19.81	20.32
L1	.150	.170	3.81	4.32
Q	.220	.244	5.59	6.20
R	.170	.190	4.32	4.83
S	.520	.540	13.21	13.72
T	.620	.640	15.75	16.26
U	.065	.080	1.65	2.03

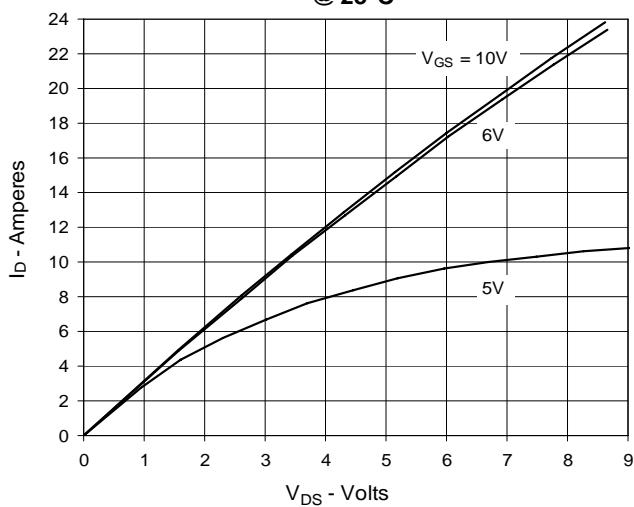
- 1 – GATE  
2 – DRAIN (COLLECTOR)  
3 – SOURCE (EMITTER)  
4 – NO CONNECTION

NOTE: This drawing will meet all dimensions requirement of JEDEC outline TO-247AD except screw hole.

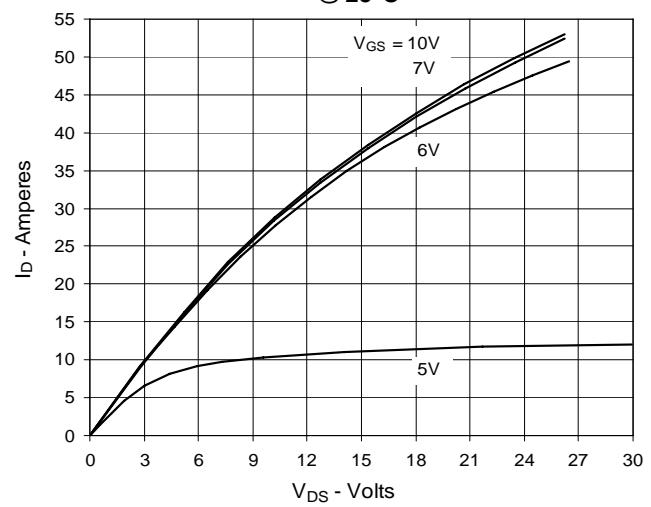
IXYS reserves the right to change limits, test conditions, and dimensions.

IXYS MOSFETs and IGBTs are covered by 4,835,592 4,931,844 5,049,961 5,237,481 6,162,665 6,404,065 B1 6,683,344 6,727,585 7,005,734 B2 one or more of the following U.S. patents: 4,850,072 5,017,508 5,063,307 5,381,025 6,259,123 B1 6,534,343 6,710,405B2 6,759,692 4,881,106 5,034,796 5,187,117 5,486,715 6,306,728 B1 6,583,505 6,710,463 6,771,478 B2

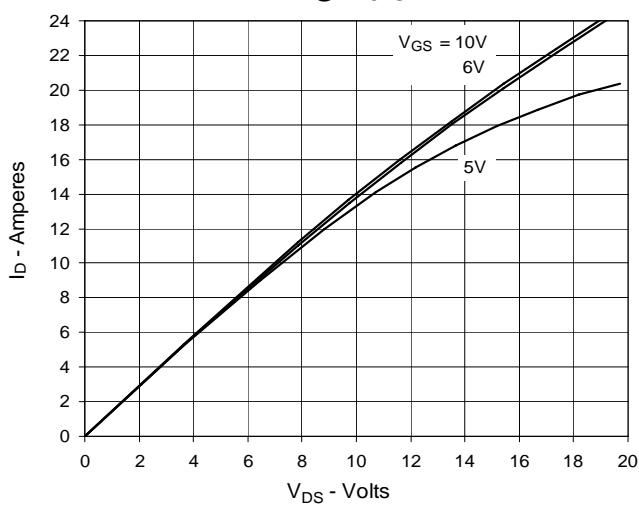
**Fig. 1. Output Characteristics  
@ 25°C**



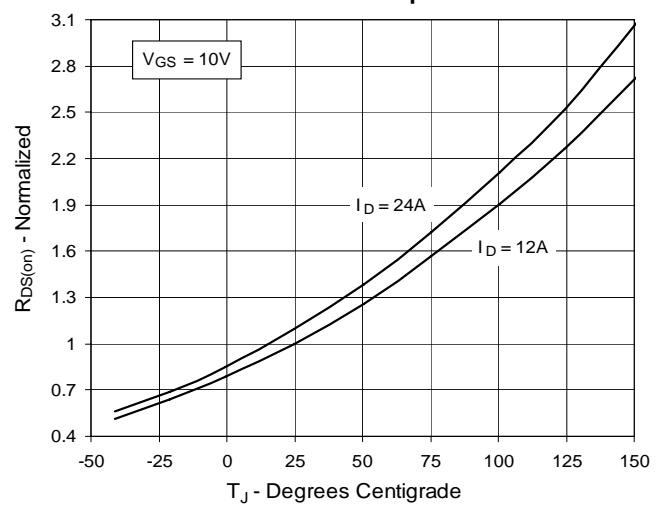
**Fig. 2. Extended Output Characteristics  
@ 25°C**



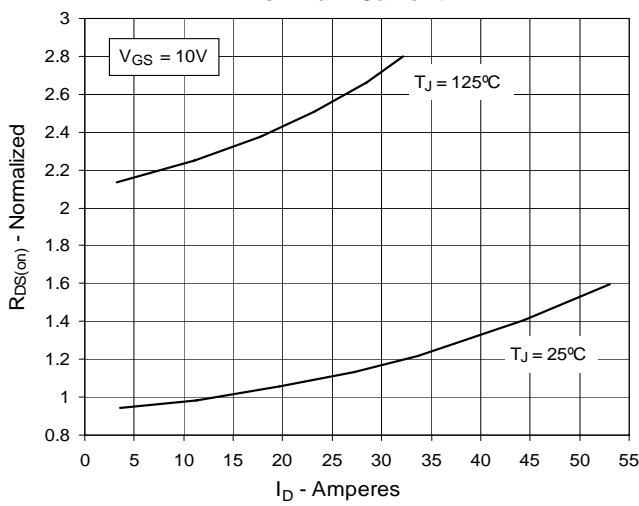
**Fig. 3. Output Characteristics  
@ 125°C**



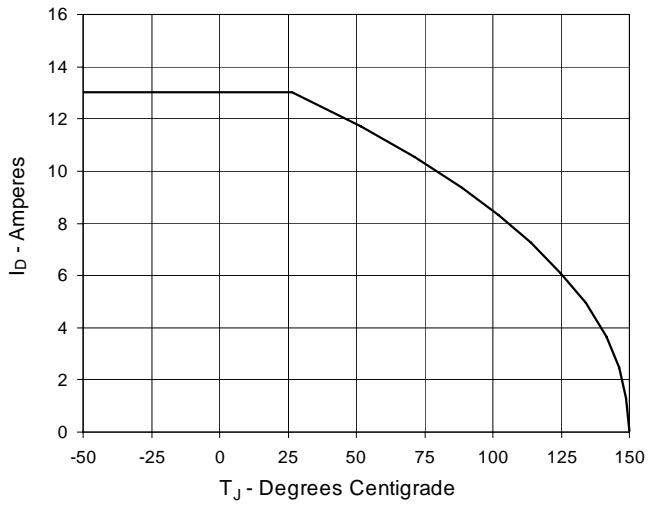
**Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 12A$  Value  
vs. Junction Temperature**

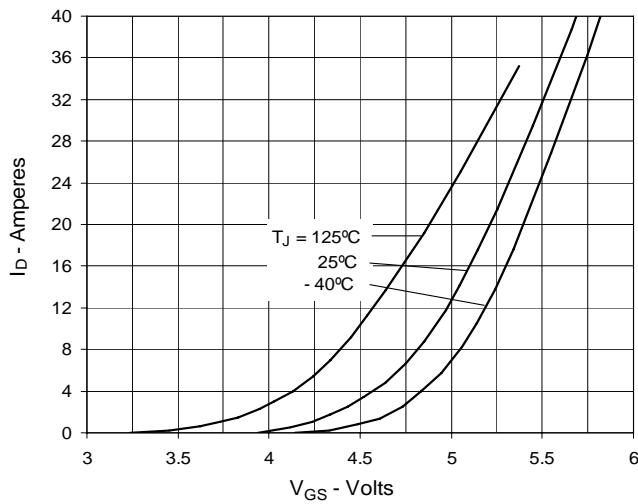
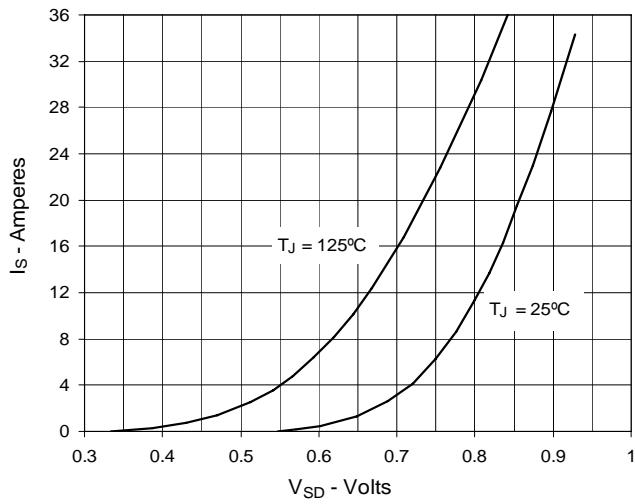
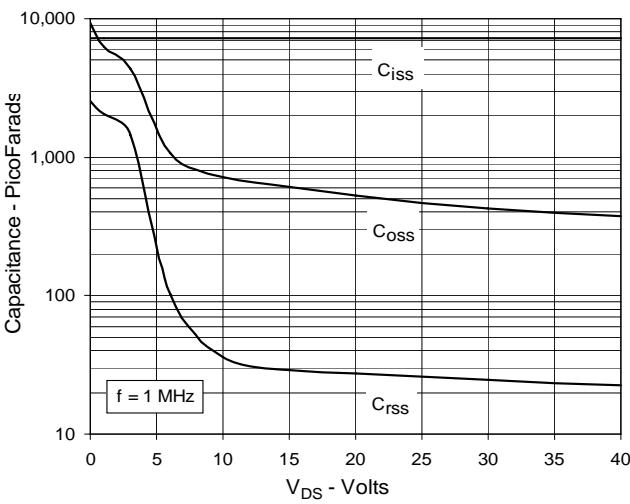
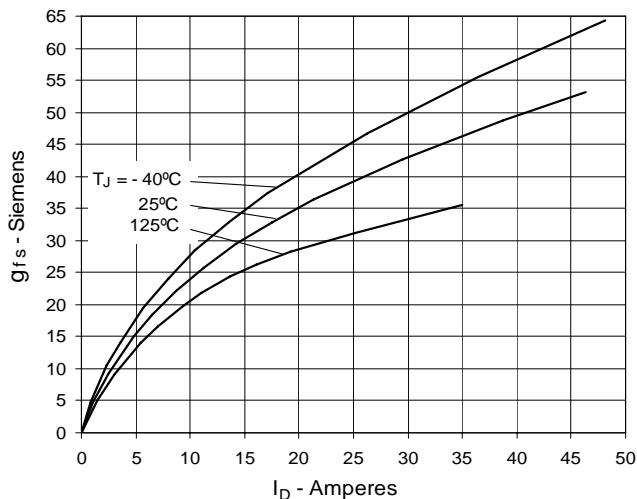
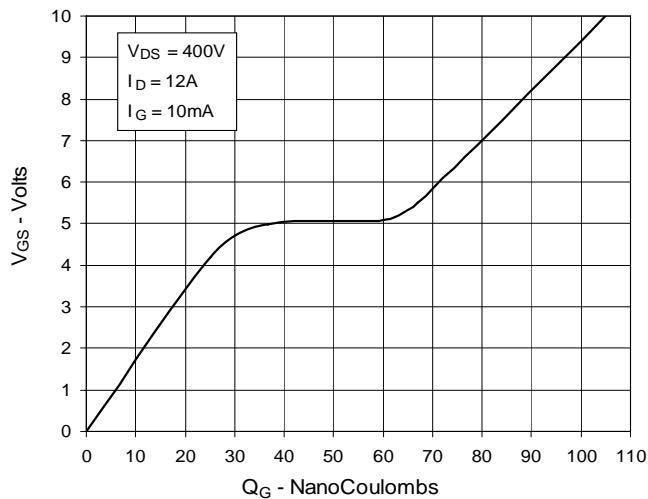
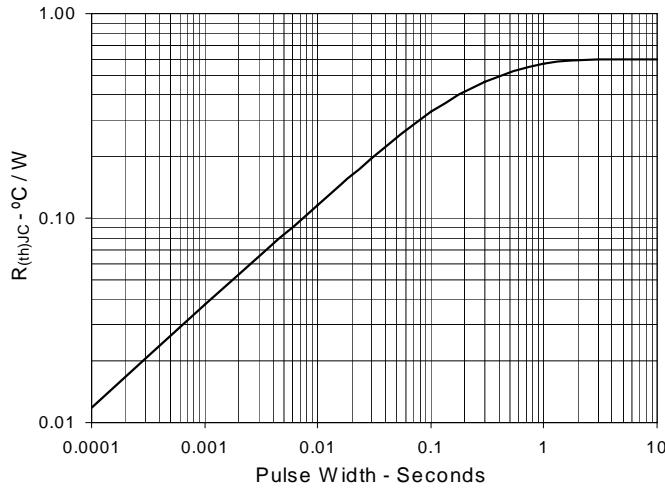


**Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D = 12A$  Value  
vs. Drain Current**



**Fig. 6. Maximum Drain Current vs.  
Case Temperature**



**Fig. 7. Input Admittance****Fig. 9. Forward Voltage Drop of Intrinsic Diode****Fig. 11. Capacitance****Fig. 8. Transconductance****Fig. 10. Gate Charge****Fig. 12. Maximum Transient Thermal Resistance**



---

Disclaimer Notice - Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at [www.littelfuse.com/disclaimer-electronics](http://www.littelfuse.com/disclaimer-electronics).

# X-ON Electronics

Largest Supplier of Electrical and Electronic Components

*Click to view similar products for [MOSFET](#) category:*

*Click to view products by [IXYS](#) manufacturer:*

Other Similar products are found below :

[614233C](#) [648584F](#) [IRFD120](#) [JANTX2N5237](#) [FCA20N60\\_F109](#) [FDZ595PZ](#) [2SK2545\(Q,T\)](#) [405094E](#) [423220D](#) [TPCC8103,L1Q\(CM](#)  
[MIC4420CM-TR](#) [VN1206L](#) [614234A](#) [715780A](#) [NTNS3166NZT5G](#) [SSM6J414TU,LF\(T](#) [751625C](#) [BUK954R8-60E](#) [NTE6400](#) [SQJ402EP-](#)  
[T1-GE3](#) [2SK2614\(TE16L1,Q\)](#) [2N7002KW-FAI](#) [DMN1017UCP3-7](#) [EFC2J004NUZTDG](#) [ECH8691-TL-W](#) [FCAB21350L1](#) [P85W28HP2F-](#)  
[7071](#) [DMN1053UCP4-7](#) [NTE221](#) [NTE222](#) [NTE2384](#) [NTE2903](#) [NTE2941](#) [NTE2945](#) [NTE2946](#) [NTE2960](#) [NTE2967](#) [NTE2969](#) [NTE2976](#)  
[NTE6400A](#) [NTE2910](#) [NTE2916](#) [NTE2956](#) [NTE2911](#) [DMN2080UCB4-7](#) [TK10A80W,S4X\(S](#) [SSM6P69NU,LF](#) [DMP22D4UFO-7B](#)  
[DMN1006UCA6-7](#) [DMN16M9UCA6-7](#)